

NASA ULTRA-SENSITIVE MINIATURE ACCELEROMETER

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ABSTRACT

Using micro-machined silicon technology, an ultra-sensitive miniature accelerometer can be constructed which meets the requirements for microgravity experiments in the space environment. Such an accelerometer will have a full scale sensitivity of 10^{-2} g a resolution of 10^{-8} g, low cross-axis sensitivity, and low temperature sensitivity. Mass of the device is approximately five grams and its footprint is 2 cm x 2 cm. Innovative features of the accelerometer, which are patented, are: electrostatic caging to withstand handling shock up to 150 g, in-situ calibration, in situ performance characterization, and both static and dynamic compensation. The transducer operates on a force balance principle wherein the displacement of the proof mass is monitored by measuring tunneling electron current flow between a conductive tip and a fixed platen. The four major parts of the accelerometer are tip die, incorporating the tunneling tip and four field plates for controlling pitch and roll of the proof mass; two proof mass dies, attached to the surrounding frame by sets of four "crab-leg" springs; and a force plate die. The four parts are fuse-bonded into a complete assembly. External electrical connections are made at bond pads on the front surface of the force plate die. Materials and processes used in the construction of the transducer are compatible with volume production.

INTRODUCTION

Microgravity accelerometers used in the harsh environment of space must measure extremely small static and near-static events. Typical applications are experiments on the space shuttle, free flyers, space station, sounding rockets, etc.

The Micro Gravity Acceleration (MGA) sensor is a spring/mass type using a unique "crab-leg" spring support configuration and electrostatic platen force for control of mass movement. Design features of the MGA sensor include electron tunneling tip position detection, electrostatic force feedback, pitch and roll control, electrostatic compensation, and low off-axis sensitivity. A tunneling electron tip provides precision proof mass positioning and measurement for closed-loop

control of the sensor. The resulting accelerometer will have a small, 2 cm x 2 cm x 0.6 cm package envelope, a proof mass of 0.2 gm., and a light, 5 gm. (2 oz) total weight. The targeted operating amplitude range is 10^{-8} to 10^{-2} g with 10^{-9} g resolution and a natural resonance of 12.5 Hertz. The sensitivity, small size and light weight package characteristics are desirable attributes to monitor and control microgravity experiments. The electrostatic force platen design can provide an offset for a constant acceleration field (i.e. Earth gravity). Microgravity acceleration changes can be sensed and measured in the presence of a constant field up to 1 g. The electrostatic parking design provides non-operational high acceleration (150 g) load tolerance.

The new simplified lightweight microgravity accelerometer uses micro-machined silicon technology. The spring-supported transducer employs a force balance principle based on electrostatically attracted platens. This technique is expected to provide an ultra high sensitivity when the tunneling tip measurement of proximity error is used to hold the mass motionless via a current feedback process. The variation in voltage necessary to maintain mass positioning as a result of this feedback loop will be related to the square root of variation in magnitude of the applied acceleration.

The unique mass-support mechanism uses a dual, four-point crab leg suspension arrangement. This support method minimizes the undesirable cross-axis sensitivity typically present with small transducers. The supported mass is brought into close proximity to the tunneling tip and held stationary using a feedback technique. An added benefit of this technique is that in situ calibration is possible. A known dynamic electrostatic excitation may be applied to the force plate which simulates the result of, and is indistinguishable from, an actual acceleration. Verification of transducer performance and sensitivity values can be undertaken in this manner.

The characteristics cited for improvement over current microgravity accelerometer technology include: a decreased size and mass, higher sensitivity, simplified calibration procedures, health monitoring, and a decreased cost per unit. A novel feature of the desired transducer is that it can be dynamically calibrated in place. In-place calibrations are expected to be highly important when sensitivity changes of the unit might take place over long periods of time, such as during operation on space station or long duration planetary missions.

I. SPECIFICATIONS

The specific technical objectives for the microgravity accelerometer development are:

1. Dimensions: $< 2 \times 2 \times 0.6$ cm
2. Total mass: < 5 grams
3. Proof mass: 0.2 grams

4. Amplitude precision range: 10^{-8} to 10^{-2} g
5. Resolution: 10^{-9} g
6. Bandwidth: Static to 10 Hz
7. Cross Axis Sensitivity: < 0.1% of reading
8. Temperature sensitivity: < 0.01%/°C
9. Operating temperature limits: -20 to +80°C
10. Non-operating temperature limits: -40 to +90°C
11. Non-operating shock limit without affecting calibration: > 150 g
12. In-situ static and dynamic calibration during operation
13. In-situ health monitoring and characterization
14. Self test/calibration: internal electrostatic force
15. System interface: Micro computer regulated precision ADC and DAC units

II. INNOVATIONS

The MGA sensor is an autonomous transducer which provides functional verification as well as perpetual calibration, offset and coefficient compensation. Several innovative features are unique and are patented.

A. Calibration

The electrostatic attractive force exerted by an electric field between the force plate and the proof mass cannot be differentiated from either the seismic acceleration or mechanical restoration forces. The desired force arises from an applied voltage on the force plate which is previously correlated to a predetermined force on the movable member. By observing the response of the feedback controller to the applied voltage on the force plate, the entire device may be calibrated. In fact, a large range of applied voltages corresponding to a range of applied forces may be used in succession to internally calibrate the micromachined transducer. The advantage is that the device is readily calibrated or re-calibrated remotely and with great precision without any external calibration equipment of the type typically required.

B. Characterization

In order to characterize various parameters (such as frequency response) of a micro-machined transducer, the desired force applied by the control apparatus is a test stimulus signal. This range of parameters may include, for example, frequency response, phase response, linearity, hysteresis and the like.

C. Static and Dynamic Compensation

It may be desired to compensate for a large ambient force so that only small differentials are measured by the micro-machined transducer. The desired force is one which is equal and opposite to the force exerted on the movable member by the ambient force. This type of compensation requires the desired force to be fairly constant over time, and is therefore a type of static compensation.

Three micro-machined accelerometers may be integrated in an inertial sensor, each accelerometer being aligned, to within a manufacturing error, along a respective one of three orthogonal axes. The resulting cross-coupling between measurements otherwise deemed to be orthogonal is measured precisely after assembly of the inertial measurement device. During calibration and operation, the vector forces are measured using two known orthogonal forces to determine the proper correction for the third individual sensor. The same process is repeated to determine the correction for each of the sensors in a triaxial configuration. These correction factors are then applied to the appropriate accelerometer's force plate and the cross axis error in the measured data is compensated for.

A fixed bias may be deployed in determining the static characterization of a transducer, such as providing "free" levitation of a sensor element in a fixed gravitational field.

A small single cell battery of about a volt, can create a large attractive force between two micro-structured platens. With a good insulator, the leakage current is negligible, permitting maintenance of a retention force for the cell life of about a decade. In micro-structured accelerometer, application of this electrostatic retention facilitates a simple mechanism for caging the proof mass that will withstand accelerations in excess of 150 g for launch, etc.

III. MECHANICAL DESCRIPTION

The transducer design is based on a four die configuration as shown in Figure 1. The top die in the figure is referred to as the tip die which is shown in more detail in Figure 2. The tip die has at its center an electron tunneling tip. The tip will be approximately $3.75\ \mu\text{m}$ high. Two identical dies are bonded together to form the proof mass. These dies are comprised of a border region and the proof mass as shown in the center of Figure 3. The proof mass is 1 cm ($10,000\ \mu\text{m}$) across. The lowest die is referred to as the force plate. Figure 4 presents the top and bottom views of this die.

IV. CONSTRUCTION

A. Tip Die

The tip die, the most complicated structure in the assembly, has its basic fabrication process illustrated in Figure 5. Key specifications of the tip die are listed in Table 1. It not only incorporates the tunneling tip, but contains 4 field plates to control the pitch and roll of the proof mass as well as its position. The tip die must also accommodate the bonding method use to assemble the four separate dies that comprise the accelerometer. Two separate metal layers are required. The first layer is isolated from the second by a $0.5\text{ }\mu\text{m}$ oxide layer. The first metal layer is used as the tip metal. A three metal composite is used consisting of chrome/gold/chrome. Chrome layers are used to enhance adhesion to the substrate (nitride coated silicon) and to the isolation oxide layer. The top chrome layer of this composite metal layer is removed to expose the gold layer as the tip metal.

The second metal layer, the same metal used as the bonding layer, is aluminum/germanium, the preferred choice because it is easily deposited, inexpensive and has a low bonding temperature.

The center region of the die is recessed with respect to the bond perimeter and bond pads. This is required to obtain a spacing between the field plates and the proof mass. When this die is bonded to the proof mass, the perimeter will form a hermetic seal with the bond pads, mechanically bonded and electrically connected to their counterparts on the proof-mass die. This electrical connection scheme is a key feature of the design. By interconnecting the die in the bonding processes, all electrical connections to the completed accelerometer can be made from its front surface.

The electrically insulating oxide layer is removed from the tip and its surrounding area, exposing the tip metal. The electrical contact to the tip is accomplished with the first metal layer which is connected by a single thin lead to the bond pad. The second metal layer which forms the field plates, bond perimeter and bond pads is deposited above the first metal layer. The cross in the center of the bond perimeter, which is electrically grounded, is used to shield the tip metal lead from the influence of the electric fields that will exist in the vicinity of the field plates. Because of the recessed nature of the center of the die, the center cross of the bond perimeter will not take part in the bonding process. The cross is open at the very center to expose the tip below.

To connect the force plates electrically to the bond pads, holes are cut in the oxide layer above the first metal in the vicinity of the force plates. This allows the force plates to contact the first metal layer. The first metal layer is patterned in such a way as to connect each force plate electrically to its associated bond pad. The bond pads also contain a connection between first and second metal.

B. Proof Mass Die

Key specifications of the proof mass die are given in Table 2 and the basic steps in the fabrication process are shown in Figure 6. The proof mass is assembled from two identical die. The top dimension is 1 cm or 10,000 μm . The proof mass is held to the surrounding frame by a set of springs affectionately referred to as 'crab legs.' The target thickness of the crab legs is 25 μm . Each individual crab leg is divided into three spring sections, two short ones and one long one. The length of the short sections is 5000 μm , but the length of the long spring is 9800 μm , due the requirement to clear the corner ties. The corner ties play no role in the normal motion of the proof mass and do not alter the stiffness of the device in its sensitive axis. These ties are added to increase the stiffness to pitch, roll and yaw.

The proof mass die is maintained at essentially ground potential and the surface of the proof mass is completely covered by metal. At the perimeter of the die, electrical contact between bond pads is routed to facilitate the scheme of front surface contact only, as described above.

The eutectic bonding metal is applied before the anisotropic etch procedure to prevent metal deposition on the backs of the springs.

C. Force Plate Die

Key specifications of the force plate die appear in Table 3 and the basic steps in the fabrication process are shown in Figure 7.

The force plate die, similar to the tip die, uses a two metal process to provide a bond perimeter which is not electrically connected to the force plate. A contact pad to this perimeter metal is provided in order to set the potential. The force plate is fabricated in first metal, which may simply be a single chrome layer similar to that used on the tip wafer. The force plate must be covered with a thin 1000 Å oxide layer. The purpose of this oxide layer is to prevent an electrical contact between the proof mass and the force plate when the proof mass is being clamped electrostatically. Choices for the bond perimeter and contact layer (second metal) are identical to those described for the tip wafer.

The 'top view' section of Figure 4 shows the locations of the bond pads and specifies their various functions

CONCLUSIONS

Silicon micromachining is rapidly becoming the dominant method for producing state-of-the-art sensors in the world today. Even laboratory tunneling tip accelerometers have been developed but, until now no one has resolved how the delicate mechanisms of sensitive accelerometers can be protected and a robust sensor engineered.

The recursive design process that resolved the mechanisms and machining processes to realize them has been arduous but rewarding. The MGA sensor described in this paper will provide experimenters with the capability for highly sensitive acceleration measurements using a device of extremely small size and mass. This sensor has patented innovative features which include in situ calibration, in-situ characterization and self test, state and dynamic compensation, and caging. The sensor also has low cross-axis sensitivity and negligible temperature sensitivity ($10^{-5} \mu\text{g}/^\circ\text{C}$). Materials and processes used in the construction of the transducer are compatible with volume production.

ACKNOWLEDGMENTS

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Table 1: Key Specifications of the Tip Die

Design Characteristic	Specification	Tolerance
Tip to Ground Capacitance	100 pf	+/-20 pf
Control Plate to Substrate Capacitance	100 pf	+/-20 pf
Control Plate to Proof Mass Capacitance	100 pf	+/-1 μf
Control Plate to Tip Ground Capacitance	0.2 pf	max.
Voltage to overcome 1g	5	+/-1
Tip to Proof Mass Proximity	0	+/-0.2 μm
Tip Height	3.5 μm	+/-0.5 μm
Bond Metal Thickness	1 μm	+/-0.1 μm
Insulating Layer Thickness	0.5 μm	+/-0.05 μm

Table 2: Key Specifications of the Proof Mass Die

Design Characteristic	Specification	Tolerance
Mass	0.18 gm	+/-0.005 gm
Volume of Proof Mass	$7.55 \times 10^{-2} \text{ cm}^3$	
Spring Thickness	25 μm	+/-5 μm
Spring Width	100 μm	+/-5 μm
Spring Length	5000/9800 μm	+/-5 μm

Table 3: Key Specifications of the Force Plate Die

Design Characteristic	Specification	Tolerance
Force Plate to Substrate Capacitance	$5 \times 10^{-2} \mu f$	$+/-2 \times 10^{-2} \mu f$
Voltage to overcome 1g	10	$+/-2$
Bond Metal Thickness	$1 \mu m$	$+/-0.1 \mu m$
Insulating Layer Thickness	1000 Å	$+/-250 \text{ Å}$
Depth of Depression	$5 \mu m$	$+/-0.05 \mu m$
Max. Holding Voltage	10	
Holding Force @ 1.4v	96 g to 265 g	

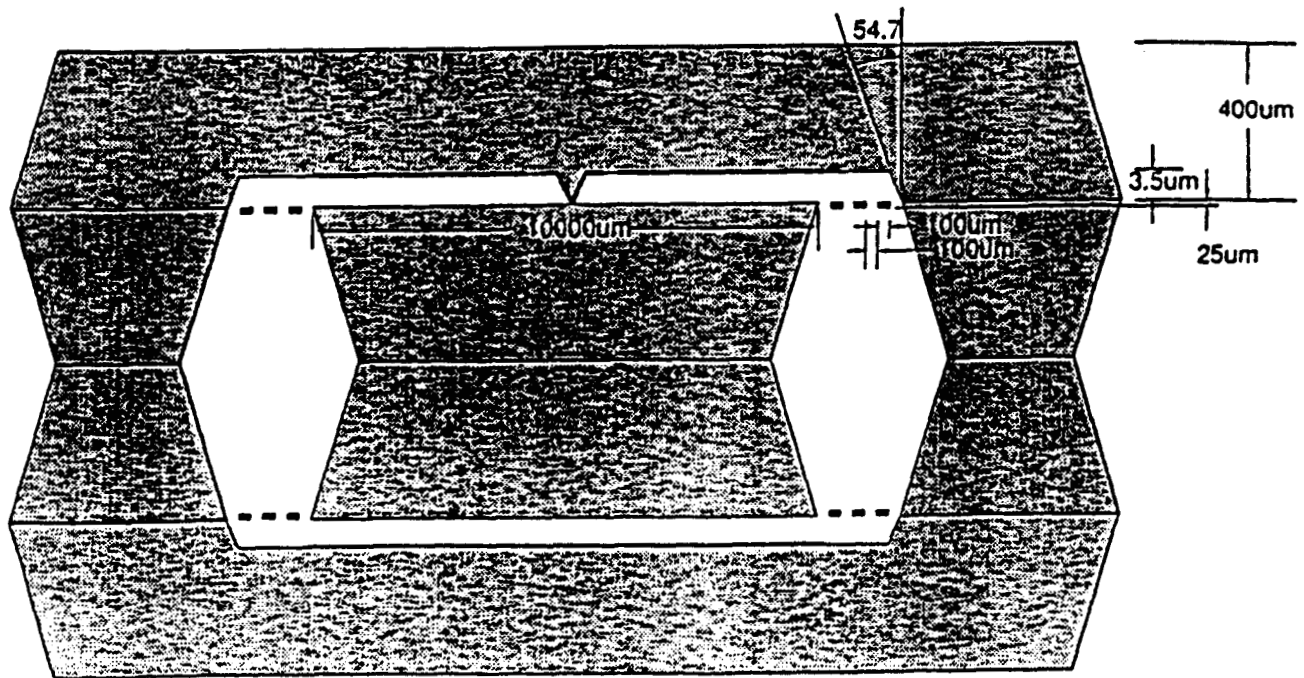


Figure 1 Accelerometer Assembly.

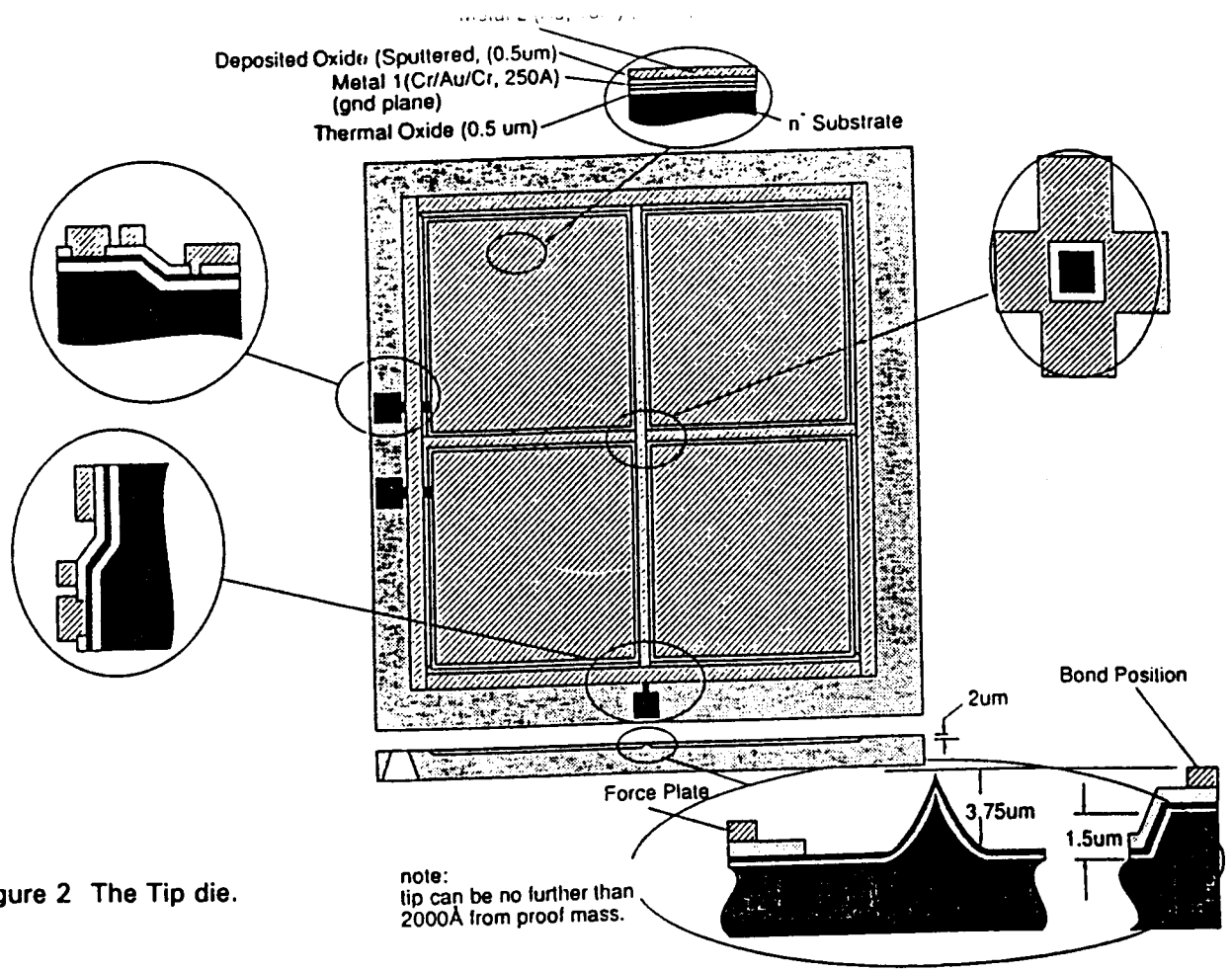


Figure 2 The Tip die.

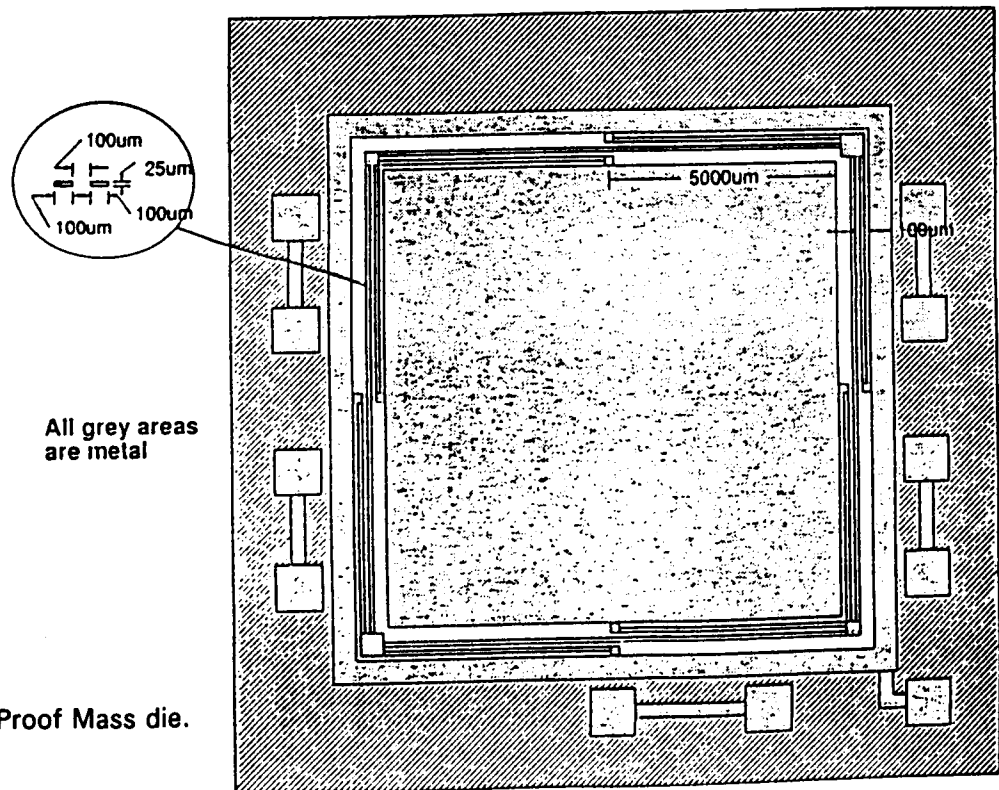


Figure 3 The Proof Mass die.

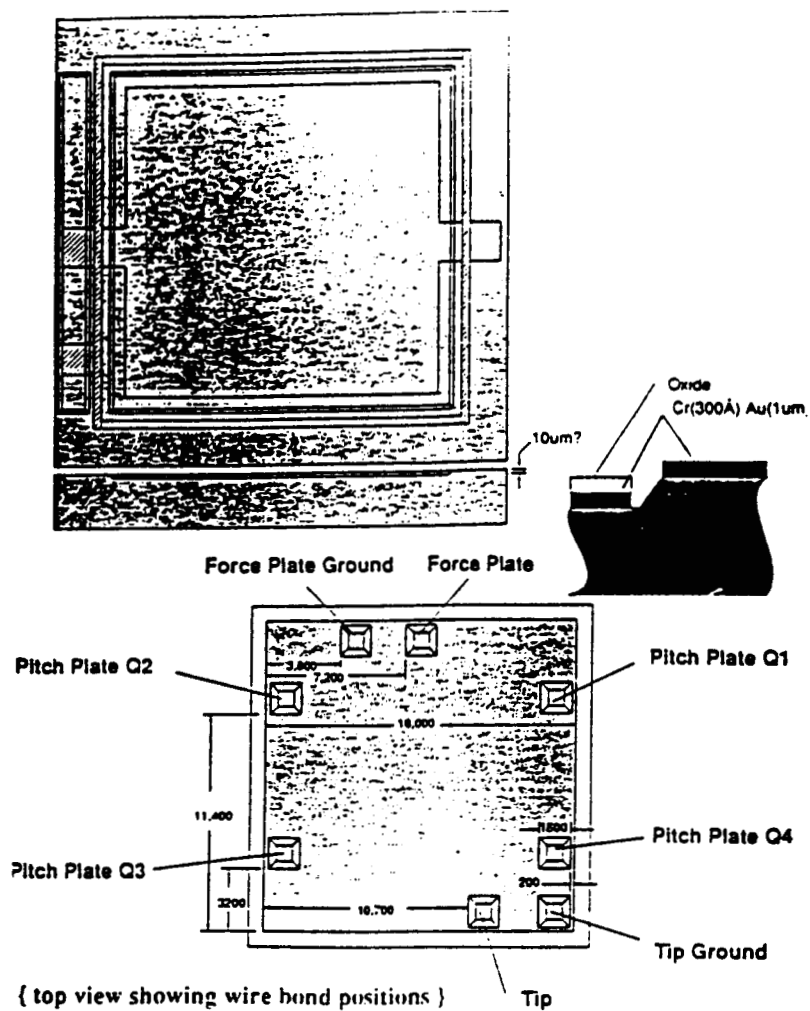


Figure 4 Force plate die.

Dep oxide/nitride
Double sided alignment
Backside KOH
Plasma Strip front Nitride
Thermal Oxide (1um)
Pattern so
Plasma Etch everything
else



Plasma etch #2 to define
bond penmeter.



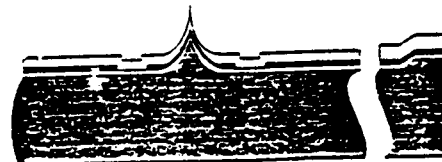
Reoxidize to further
sharpen sp.



Clear Oxide.
ReOxidize.



Cd/Au/Cr dep and pattern
Dep 5000Å Oxide
pattern and cut oxide



Dep and pattern Cr/Au
Cut Oxide off tip



Figure 5 Tip Die fabrication process.

Oxidize Water (200Å)
 Dep Silicon Nitride (1000Å)
 double sided align
 Cut nitride/oxide
 re-pattern bottom for KOH
 Cut Nitride
 Deep KOH Etch



Pattern Front for Shallow KOH
 Cut nitride/oxide
 Shallow KOH Etch



Thin Oxide
 Cr/Au/Cr on Front



Pattern Cr/Au/Cr or Cr on front
 Dep Oxide on front (1micron)
 sputtered and annealed at
 450 C, 30min.
 Pattern and cut oxide
 Dep Cr/Au Metal2
 Pattern Cr/Au/Si

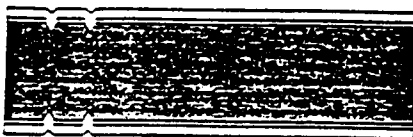


Figure 6 Proof mass die fabrication process.

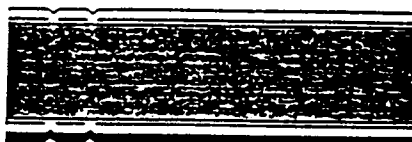
Oxidize Water (1000Å)
 double sided align
 Shallow KOH etch



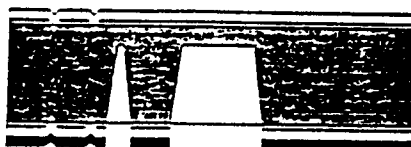
Deposit Silicon Nitride



Deposit Cr/Au on back



Cut Bottom Au
 Pattern Nitride
 Etch Nitride/Oxide (Plasma)
 KOH Etch Back
 Plasma etch Nitride on back to
 remove tabs!



Deposit Cr/Au on
 Front (300Å Cr/3000Å Au)
 Cut Top AU
 Pattern Nitride/Oxide
 Cut top Nitride/Oxide (Plasma)
 Third KOH Cut
 Deposit Silicon on Back side

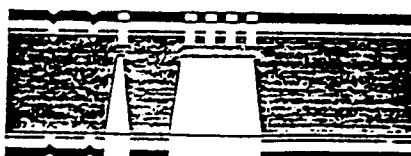


Figure 7 Force plate die fabrication process.

Discussion

Question: *I wondered if you looked at the stability of this tip ?*

Answer: We haven't put the thing together yet in its entirety. I don't think there is much issue about the stability of silicon as a material and the precision with which you can machine and those other issues. So if you are talking about dimensional stability of the device itself, that is not going to be an issue. In terms of the tip, an issue will be breaking it or contaminating it, but, again, even in terms of the contamination we are looking at in these systems, we can have it in a vacuum and there is not going to be any oxidation. I am not anticipating any problems with that.

Question: *Any direct mechanical connection between the case and the proof mass, and how those change with temperature and time will affect bias. How do you stabilize those grab springs ?*

Answer: Well, in silicon I don't think we are going to have to worry about stabilizing it.

Question: *Those dimensions will shift as the thing heats up or cools off. Will that be of any effect ?*

Answer: As I have indicated, I do not think there is going to be a problem. It is not going to be a stability problem. The dimensional changes are still quite small, and I don't think they are going to have an effect on this. The other one that we were looking at was what the growth of the pier would be due to thermal expansion, and because we are only working with micrometers, that is not a significant issue. But again, we have in situ calibration in this, and we will be tracking those temperature variations and can accommodate them.